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FAIRCHILD

SEMICONDUCTOR®

FDS8842NZ N-Channel PowerTrench[®] MOSFET

40 V, 14.9 A, 7.0 mΩ

Features

- Max $r_{DS(on)}$ = 7.0 m Ω at V_{GS} = 10 V, I_D = 14.9 A
- Max $r_{DS(on)}$ = 11.6 m Ω at V_{GS} = 4.5 V, I_D = 11.6 A
- HBM ESD protection level of 4.4 kV typical(note 3)
- High performance trench technology for extremely low r_{DS(on)} and fast switching
- High power and current handling capability
- Termination is Lead-free and RoHS Compliant

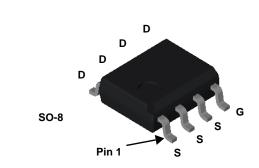


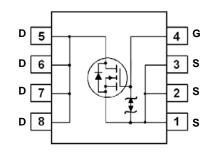
General Description

The FDS8842NZ has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest $r_{DS(on)}$ while maintaining excellent switching performance.

Applications

- Synchronous Buck for Notebook Vcore and Server
- Notebook Battery
- Load Switch





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Para	meter		Ratings	Units	
V _{DS}	Drain to Source Voltage			40	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous			14.9	Α	
D	-Pulsed	-Pulsed S				
E _{AS}	Single Pulse Avalanche Energy		(Note 4)	253	mJ	
D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5	w	
P _D	Power Dissipation	(Note 1b)	1.0	vv		
T _J , T _{STG}	Operating and Storage Junction Tempe	erature Range		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/vv

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8842NZ	FDS8842NZ	SO8	13 "	12 mm	2500 units

February 2009

Тур	Max	Units
		V
35		mV/°C
	1	μA
	±10	μA
1.9	3.0	V
-6		mV/°C
5.6	7.0	
6.7	11.6	mΩ
8.9	11.1	
111		S
2890	3845	pF
340	455	pF
220	330	pF
0.8		Ω

FDS8842NZ N-Channel Power Trench[®] MOSFET

BV_{DSS} Drain to Source Breakdown Voltage $I_D = 250 \ \mu A, \ V_{GS} = 0 \ V$ ΔBV_{DSS} Breakdown Voltage Temperature $I_D = 250 \ \mu\text{A}$, referenced to 25 °C ΔT_{J} Coefficient $V_{DS} = 32 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ Zero Gate Voltage Drain Current Gate to Source Leakage Current $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ **On Characteristics** Gate to Source Threshold Voltage $V_{GS}=V_{DS},\ I_{D}=250\ \mu A$ V_{GS(th)} $\Delta V_{GS(th)}$ Gate to Source Threshold Voltage $I_D = 250 \ \mu A$, referenced to 25 °C **Temperature Coefficient** ΔT_{J} V_{GS} = 10 V, I_D = 14.9 A

Forward Transconductance $V_{DS} = 5 V, I_{D} = 14.9 A$ **g**fs **Dynamic Characteristics**

Static Drain to Source On Resistance

Electrical Characteristics T_J = 25 °C unless otherwise noted

Parameter

C _{iss}	Input Capacitance		2890	3845	pF
C _{oss}	Output Capacitance	─── V _{DS} = 15 V, V _{GS} = 0 V, ─── f = 1 MHz	340	455	pF
C _{rss}	Reverse Transfer Capacitance		220	330	pF
R _g	Gate Resistance	f = 1 MHz	0.8		Ω

V_{GS} = 4.5 V, I_D = 11.6 A

 $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 14.9 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$

Test Conditions

Min

40

1.0

Switching Characteristics

Symbol

IDSS

I_{GSS}

r_{DS(on)}

Off Characteristics

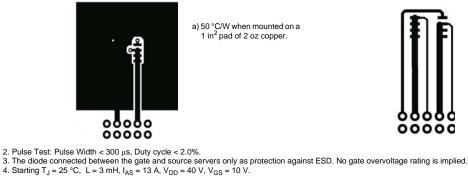
t _{d(on)}	Turn-On Delay Time			13	23	ns
t _r	Rise Time	$V_{DD} = 20 \text{ V}, \text{ I}_{D} = 14.9$ $V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 0$	A,	7	14	ns
t _{d(off)}	Turn-Off Delay Time	$v_{GS} = 10 v, R_{GEN} = 0$	5 5 2	34	54	ns
t _f	Fall Time			5	10	ns
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		52	73	nC
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V$	/ _{DD} = 20 V, _D = 14.9 A	27	38	nC
Q _{gs}	Gate to Source Charge		D = 14.9 A	8.6		nC
Q _{gd}	Gate to Drain "Miller" Charge			9.7		nC

Drain-Source Diode Characteristics

V	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 14.9 A	0.8	1.2	V	
VSD	Source to Drain Diode Polward voltage	V _{GS} = 0 V, I _S = 2.1 A		0.7	1.2 V	v
t _{rr}	Reverse Recovery Time			26	42	ns
Q _{rr}	Reverse Recovery Charge	I _F = 14.9 A, di/dt = 100 A/μs		15	27	nC

NOTES:

1. R_{0,JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



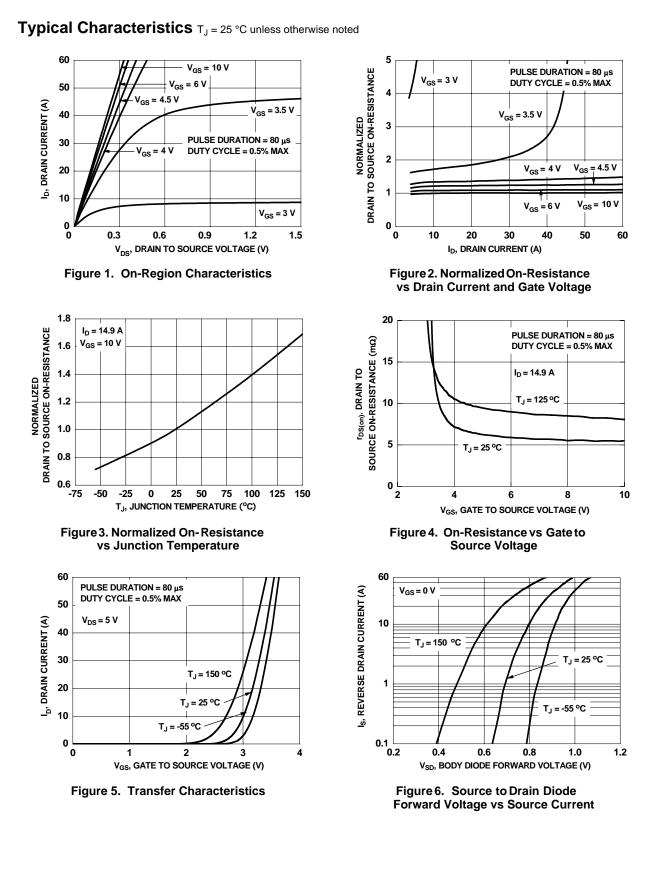
a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper.



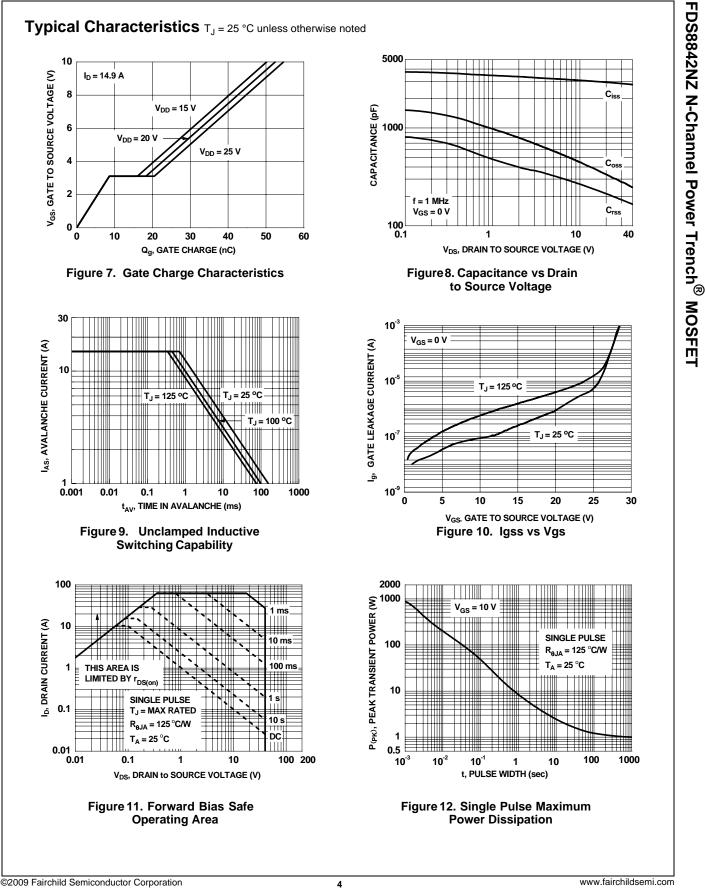
b) 125 °C/W when mounted on a minimum pad.



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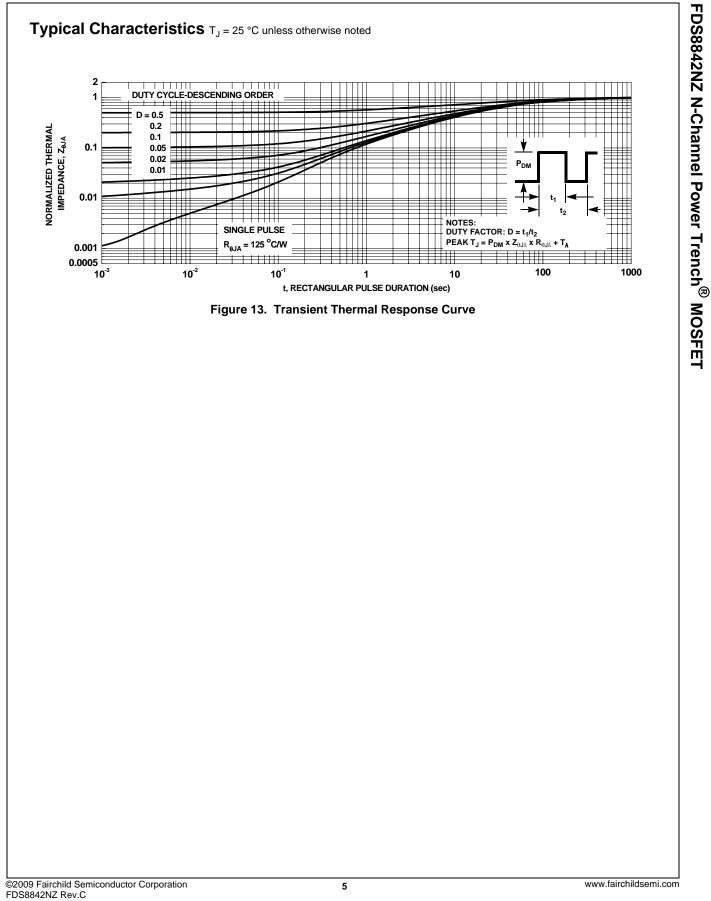


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The Power Franchise[®]

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